NSN 5962-01-575-5250

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-40.0/+85.0 degrees celsius
Features Provided:
Asynchronous and high performance and high speed and bidirectional and programmable and low noise and w/open collector
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic and transistor-transistor logic
Current Rating Per Characteristic:
25.00 microamperes output
Product Name:
Programmable eeprom logic array
Voltage Rating And Type Per Characteristic:
4.6 volts total supply
Time Rating Per Chacteristic:
7.50 nanoseconds agc threshold
Memory Device Type:
Eeprom
Special Features:
Power save mode; tristate buffer; 166.6 mhz maximum freq; w/flip flop; 120 i/os; 50kohm; adjustable slew rate; 5000 usable gates;
surface mount
Terminal Type And Quantity:
144 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Yes - demil/mli

Fiig:

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